



BC846AW-BC848CW

NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

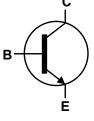
Mechanical Data

- Case: SOT323
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)

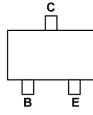


SOT323

Top View







Top View Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel	Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC846AW-7-F	AEC-Q101	K1Q	7	3,000	BC847BWQ-13-F	Automotive	K1R	13	10,000
BC846BW-7-F	AEC-Q101	K1R	7	3,000	BC847CW-7-F	AEC-Q101	K1M	7	3,000
BC846BWQ-7-F	Automotive	K1R	7	3,000	BC847CW-13-F	AEC-Q101	K1M	13	10,000
BC846BW-13-F	AEC-Q101	K1R	13	10,000	BC847CWQ-7-F	Automotive	K1M	7	3,000
BC847AW-7-F	AEC-Q101	K1Q	7	3,000	BC848AW-7-F	AEC-Q101	K1Q	7	3,000
BC847BW-7-F	AEC-Q101	K1R	7	3,000	BC848BW-7-F	AEC-Q101	K1R	7	3,000
BC847BW-13-F	AEC-Q101	K1R	13	10,000	BC848CW-7-F	AEC-Q101	K1M	7	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

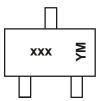
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



xxx = Product Type Marking Code (Please see Ordering Information) YM = Date Code Marking Y or \overline{Y} = Year (ex: A = 2013)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key	-			-	-			-			-	
Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V _{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V _{CEO}	45	V
	BC848		30	
	BC846, BC847		6	V
Emitter-Base Voltage	BC848	V _{EBO}	5	v
Continuous Collector Current		lc	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		I _{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 6)		R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state. 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



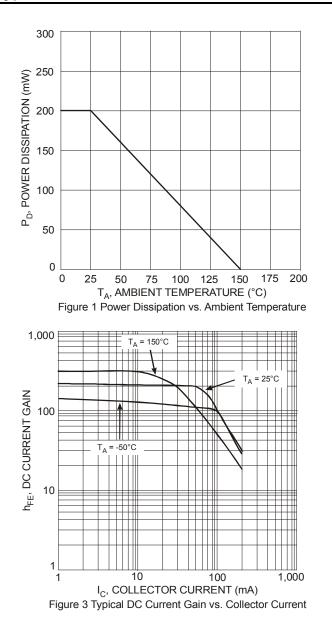
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

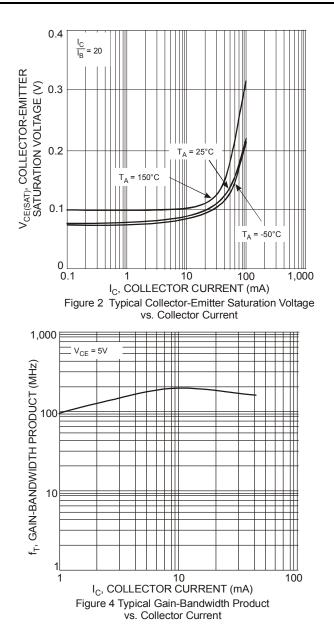
Chai	racteristic			Symbol	Min	Тур	Max	Unit	Test Condition	
		E	3C846		80					
Collector-Base Breakdown Voltage BC847			3C847	BV _{CBO}	50	—	—	V	I _C = 100μA	
		E	3C848		30					
		E	3C846		65					
Collector-Emitter Breakdown \	/oltage (Note 8)	E	3C847	BV _{CEO}	45	—	—	V	I _C = 10mA	
		H	3C848		30					
Emitter-Base Breakdown Volta	20	BC8	46, BC847	6				V	I _E = 100μΑ	
Emilier-Base Breakdown volta	ige	æ	3C848	BV _{EBO}	5	_	—	v	ιε = 100μΑ	
			Α		110	180 290	220			
DC Current Gain (Note 8)	Current Gain Gr	oup	В	h _{FE}	200		450		V _{CE} = 5.0V, I _C = 2.0mA	
		С			420	520	800			
				I _{CBO}	—	—	20	nA	V _{CB} = 30V	
Collector Cutoff Current							5	μA	V _{CB} = 30V, T _A = +150°C	
Collector Emitter Seturation M	altaga (Nata 9)			V _{CE(sat)}	—	90	250	mV	I _C = 10mA, I _B = 0.5mA	
Collector-Emitter Saturation Vo	bilage (Note 6)					200	600	IIIV	I _C = 100mA, I _B = 5.0mA	
Dago Emitter Turn On Veltage	(Nata 9)				580	660	700	mV	I _C = 2mA, V _{CE} = 5V	
Base-Emitter Turn-On Voltage				V _{BE(on)}	_	_	770	mv	I _C = 10mA, V _{CE} = 5V	
Dago Emitter Seturation Valta	na (Nata 9)			N/		700		mV	I _C = 10mA, I _B = 0.5mA	
Base-Emitter Saturation Volta				V _{BE(sat)}	_	900		mv	I _C = 100mA, I _B = 5mA	
Output Capacitance				C _{obo}	_	3	4.5	pF	V _{CB} = 10V, f = 1.0MHz	
Transition Frequency			f⊤	100	300	_	MHz	V _{CE} = 5V, I _C = 10mA, f = 100MHz		
Noise Figure			NF	_	_	10	dB	V_{CE} = 5V, I _C = 200µA R _S = 2kΩ, f = 1kHz Δ f = 200Hz		

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

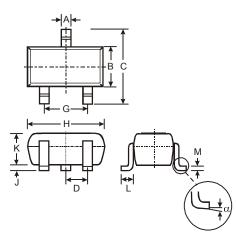






Package Outline Dimensions

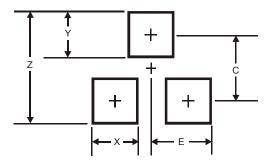
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323								
Dim	Min	Max	Тур					
Α	0.25	0.40	0.30					
В	1.15	1.35	1.30					
С	2.00	2.20	2.10					
D			0.65					
G	1.20	1.40	1.30					
н	1.80	2.20	2.15					
J	0.0	0.10	0.05					
κ	0.90	1.00	1.00					
L	0.25	0.40	0.30					
М	0.10	0.18	0.11					
α	0°	8°	_					
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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